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### SYNTHETIC METALS

## Vibrational Spectroscopy study of doping induced charged defects in a series of $\alpha,\alpha'$ -Dimethyl end-capped Oligothiophenes

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#### Abstract

We present some preliminary results of a vibrational spectroscopic investigation carried out on a series of  $\alpha,\alpha'$ -dimethyl end-capped oligothiophenes doped with iodine. The evolution of the doping-induced infrared bands has been followed by means of in situ FT-IR spectroscopy, by allowing thin films of neutral oligothiophenes to react with dry iodine vapours at different concentrations. FT-Raman spectra recorded on powdered samples of I2-doped  $\alpha,\alpha'$ -dimethylquinquethiophene indicate the existence of a polaron-type defect.

Keywords: (Infrared and Raman spectroscopy, polythiophene and derivatives)

#### 1. Introduction

Oligomers are currently being studied as model compounds of polyconjugated polymers. Oligothiophenes suffer, though, from the inherent reactivity upon doping of the  $\alpha$ -carbon atoms at both side chain ends. This instability may be overcome by blocking these  $\alpha$ -positions with alkyl substituents [1].

The defects induced by the ionization of the materials originate new features in the IR spectrum, which are associated with electronic transitions

involving midgap electronic levels [2-3].

Raman spectroscopy can also provide valuable structural information on these charged domains in doped conducting polymers and oligomers [4]. However, only very few data of acceptable quality are so far available for ionized molecules.

In this communication, we report on a self-localized excitation which occurs for iodine doped solid samples of  $\alpha,\alpha'$ -dimethyl-quinquethiophene. These data enable us to inspect the vibrational structure of the radical cation of Me-(Th)5-Me.

#### 2. Experimental Section

The synthesis and purification of the compounds have been published elsewhere [5]. All IR measurements were carried out by using a demountable cell for gases. Thin films of the neutral compounds were deposited onto NaCl windows and

doped by slow in situ sublimation of solid iodine at room temperature. IR spectra were collected with a Perkin Elmer 1760 X FT-IR spectrometer under dry Ar gas. Raman spectra were recorded on a Bruker RFS 100 FT-Raman spectrometer, with a 1064 nm exciting line.

#### 3. Results and Discussion

#### 3.1. Infrared spectra

Figure 1 shows some infrared absorption spectra collected during the chemical ionization of a thin film of Me-(Th)5-Me, at different times of exposure to iodine vapours. Electronic absorption measurements [1] performed on these end-capped oligothiophenes showed that, in each case, the iodine doping could yield only the first oxidized species (attributed to a radical cation), that are characterized by two subgap peaks (i.e., at 1.57 and 0.86 eV for a thin film of I2-doped Me-(Th)5-Me).

By considering the evolution of the infrared spectrum from the neutral state to the first oxidized state, we firstly notice that both band frequencies and intensities are significantly affected. A close look at the details shows that the ionization induces the quick appearance of at least six new IR absorptions at 1414, 1327, 1162, 1099, 993 and 946 cm<sup>-1</sup>, whose intensity increases with increasing doping level.

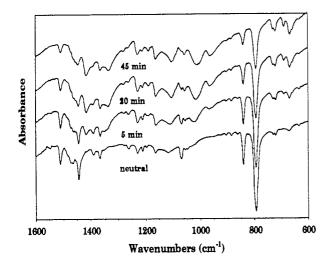


Fig. 1. FT-Infrared spectra recorded in situ during the oxidation process of  $\alpha,\alpha'$ -dimethyl end-capped quinquethiophene.

#### 3.2. Raman spectra

The FT-Raman spectrum of the radical cation of Me-(Th)5-Me is shown in Fig. 2. In the C=C stretching region, between 1600-1400 cm<sup>-1</sup>, we clearly observe four strong doping induced lines, centered at 1483, 1462, 1440 and 1422 cm<sup>-1</sup>, which are accompanied by another weak line at 1520 cm<sup>-1</sup>. These Raman bands are correlated with the bands of neutral Me-(Th)5-Me centered at 1562, 1525, 1481, 1474 and 1450 cm<sup>-1</sup> (see Fig. 3) [6,7]. Similar data have been reported by Furukawa et al. [4] for the radical cation of unsubstituted Th5.

For bands below 1400 cm<sup>-1</sup>, the measured frequencies upon doping do not drastically differ from the corresponding values in the neutral molecule. Thus, Raman lines at 1224, 1164, 1071, 1050, 732 and 697 cm<sup>-1</sup> of the radical cation are correlated to bands at 1219, 1160, 1049, 734 and 695 cm<sup>-1</sup> of the neutral molecule. In this energy region, one of the main spectral differences between both molecular systems concerns bands at 1224, 1164 and 732 cm<sup>-1</sup>, which clearly become more intense upon ionization. Another difference is that the sharp band around 1049 cm<sup>-1</sup> of the neutral Me-(Th)5-Me, which is due to an in-phase C-H wagging slightly coupled with CC stretches, appears split into a doublet at 1071 and 1050 cm<sup>-1</sup> in the spectrum of the radical cation.

#### 4. Acknowledgements

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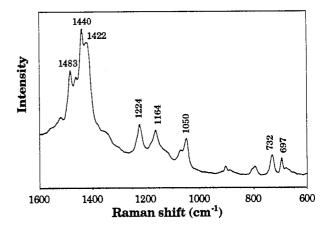


Fig. 2. FT-Raman spectrum of the radical cation of  $\alpha, \alpha'$ -dimethyl end-capped quinquethiophene.

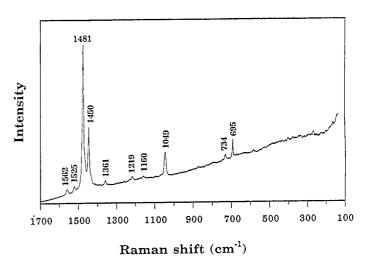


Fig. 3. FT-Raman spectrum of neutral  $\alpha,\alpha'$ -dimethyl end-capped quinquethiophene.

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